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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known			)
Application Number	09/397,898	1	7
Filing Date	09/17/99	14-	ま.
First Named Inventor	SCHULMAN	#211	7)
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MA	NPI	B.SU, V.J. GOLDMAN, and J.E. CUNNINGHAM, "Single-electron tunneling in nanometer-scale double-barrier heterostructure devices,"  Physical Review B, Volume 46, Number 12, 15 September 1992.	
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